

# **2017 IEEE 17th Topical Meeting on Silicon Monolithic Integrated Circuits in RF Systems (SiRF 2017)**

**Phoenix, Arizona, USA  
15-18 January 2017**



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# Table of Contents

## SESSION LIST

- ❖ MO1C : Emerging Topics
- ❖ MO2C : Emerging MEMS-Based Circuits
- ❖ MO3C : Broadband & Photonics
- ❖ TU1C : mmWave & THz Circuits
- ❖ TU3P : Joint RWW Interactive Poster Session
- ❖ TU4C : Efficient RF Power Generation
- ❖ WE1C : Technology, Devices & Modeling
- ❖ WE2C : Advanced Wireless Transceiver

SiRF 2017 Table of Contents

---

## MO1C: Emerging Topics

*Chair: Dietmar Kissinger, IHP GmbH/TU Berlin — Co-Chair: Nils Pohl, Ruhr-University Bochum*

*Venue: Remington, 08:00 - 09:20, Monday, 16 January 2017*

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- |                  |  |
|------------------|--|
| PAGE 1<br>MO1C-1 | <b>Monolithic-Like Heterogeneously Integrated Microsystems Using Dense Low-Loss Interconnects</b><br><i>(Hanju Oh, Xuchen Zhang, Paul K. Jo, Gary S. May, Muhannad S. Bakir)</i> |
| PAGE 4<br>MO1C-2 | <b>Towards Efficient High Power mm-Wave and Terahertz Sources in Silicon: One Decade of Progress</b><br><i>(Hamid Khatibi, Ehsan Afshari)</i>                                    |
- 

## MO2C: Emerging MEMS-Based Circuits

*Chair: Mehmet Kaynak, IHP Microelectronics — Co-Chair: Hjalti Sigmarsson, University of Oklahoma*

*Venue: Remington, 10:10 - 11:30, Monday, 16 January 2017*

---

- |                   |   |
|-------------------|---|
| PAGE 9<br>MO2C-1  | <b>Applications of Gallium Nitride in MEMS and Acoustic Microsystems</b><br><i>(Mina Rais-Zadeh, Haoshen Zhu, Azadeh Ansari)</i>              |
| PAGE 12<br>MO2C-2 | <b>Accurate Calculation of MEMS Varactor Based VCO Phase Noise Using Multitone-FM Analysis</b><br><i>(Gerhard Kahmen, Hermann Schumacher)</i> |
| PAGE 15<br>MO2C-3 | <b>High Voltage Level Shifter for RF-MEMS Control Matrix with Very Low DC Current Leakage</b><br><i>(Christian Wipf, Roland Sorge)</i>        |
- 

SiRF 2017 Table of Contents

---

## MO3C: Broadband & Photonics

*Chair: Chien-Nan Kuo, National Chiao Tung University — Co-Chair: Mina Rais-Zadeh, University of Michigan*

*Venue: Remington, 13:30 - 15:10, Monday, 16 January 2017*

---

- |                   |   |
|-------------------|---|
| PAGE 19<br>MO3C-1 | <b>Millimeter-Wave Ultra-Broadband IQ Transceiver Design — Current Status and Future Outlook</b><br><i>(Hamed Alsuraistry, Ming-Hang Wu, Wen-Jie Lin, Jeng-Han Tsai, Tian-Wei Huang)</i>  |
| PAGE 23<br>MO3C-2 | <b>A 28Gb/s 3-V Optical Driver with High Efficiency in a Complementary SiGe:C BiCMOS Technology</b><br><i>(P. Rito, I. García López, Bernd Heinemann, A. Awny, A.C. Ulusoy, Dietmar Kissinger)</i>  |
| PAGE 26<br>MO3C-3 | <b>Sub-THz Source Integrated in Industrial Silicon Photonic Technology Targeting High Data Rate Wireless Applications</b><br><i>(Elsa Lacombe, Frederic Giancesello, Cedric Durand, Guillaume Ducournau, Cyril Luxey, Daniel Gloria)</i>                          |
| PAGE 30<br>MO3C-4 | <b>A 40Gb/s PAM-4 Monolithically Integrated Photonic Transmitter in 0.25<math>\mu</math>m SiGe:C BiCMOS EPIC Platform</b><br><i>(I. García López, P. Rito, D. Petousi, L. Zimmermann, M. Kroh, S. Lischke, D. Knoll, A. Awny, A.C. Ulusoy, Dietmar Kissinger)</i> |

## TU1C: mmWave & THz Circuits

Chair: Dietmar Kissinger, IHP Microelectronics — Co-Chair: Jennifer Kitchen, Arizona State University

Venue: Remington, 08:00 – 09:40, Tuesday, 17 January 2017

---

- PAGE 33  
TU1C-1      **30Gbps Wireless Data Transmission with Fully Integrated 240GHz Silicon Based Transmitter**  
*(J. Eisenbeis, F. Boes, B. Goettel, S. Malz, U. Pfeiffer, Thomas Zwick)*
- PAGE 37  
TU1C-2      **A Fully Differential 100–140GHz Frequency Quadrupler in a 130nm SiGe:C Technology for MIMO Radar Applications Using the Bootstrapped Gilbert-Cell Doubler Topology**  
*(Simon Kueppers, Klaus Aufinger, Nils Pohl)*
- PAGE 40  
TU1C-3      **Absolute mm-Wave Power Sensor Using a Switching Quad Output Stage**  
*(Jonas Wursthorn, Herbert Knapp, Jidan Al-Eryani, Klaus Aufinger, Linus Maurer)*
- PAGE 43  
TU1C-4      **An Integrated 240GHz Differential Frequency Sixtupler in SiGe BiCMOS Technology**  
*(Arzu Ergintav, Frank Herzel, Johannes Borngräber, Dietmar Kissinger, Herman Jalli Ng)*
- PAGE 47  
TU1C-5      **A SiGe:C BiCMOS Driver/Balun/Switch Function Block for a 30GHz Satcom Transmit Array**  
*(Iancu Somesanu, Hermann Schumacher)*

## TU3P: Joint RWW Interactive Poster Session

Chair: Kevin Chuang, NanoSemi Inc. — Co-Chair: Ahmet Cagri Ulusoy, Michigan State University

Venue: Atrium, 13:30 – 15:10, Tuesday, 17 January 2017

---

- PAGE 50  
TU3P-14      **0.1mm<sup>2</sup> SiGe BiCMOS RX/TX Channel Front-Ends for 120GHz Phased Array Radar Systems**  
*(Efe Öztürk, Herman Jalli Ng, Wolfgang Winkler, Dietmar Kissinger)*
- PAGE 54  
TU3P-15      **A 38GHz Low-Loss Reflection-Type Phase Shifter**  
*(Lin-Yi Huang, Yu-Ting Lin, Chien-Nan Kuo)*
- PAGE 57  
TU3P-16      **1W<0.9dB IL DC-20GHz T/R Switch Design with 45nm SOI Process**  
*(Chaojiang Li, Greg Freeman, Myra Boenke, Ned Cahoon, Umut Kodak, Gabriel Rebeiz)*
- PAGE 60  
TU3P-17      **A G Band +2dBm Balanced Frequency Doubler in 55nm SiGe BiCMOS**  
*(W. Aouimeur, J. Moron-Guerra, A. Serhan, Sylvie Lépilliet, Thomas Quémerais, Daniel Gloria, Estelle Lauga-Larroze, J.-D. Arnould, Christophe Gaquière)*
- PAGE 64  
TU3P-18      **A 180-GHz CMOS Down-Converter MMIC for Atmospheric Remote Sensing Applications**  
*(Dristy Parveg, Mikko Varonen, Amirreza Safaripour, Steven Bowers, Tero Tikka, Pekka Kangaslahti, Todd Gaier, Ali Hajimiri, Kari A.I. Halonen)*
- PAGE 68  
TU3P-19      **A 10-GS/s Track-and-Hold Circuit for a 7-Bit Square Kilometre Array ADC in 65-nm**  
*(Ge Wu, Eugene Zailer, Leonid Belostotski, James W. Haslett, Réne Plume)*
- PAGE 72  
TU3P-20      **High-Performance Elliptic Dual Balun for W-Band CMOS Transceiver**  
*(Yo-Sheng Lin, Yun-Wen Lin, Kai-Siang Lan, Ming-Huang Kao, Chih-Chung Chen, Chien-Chin Wang)*
- PAGE 76  
TU3P-21      **Ultra Sub-Wavelength Gigahertz Resonator for Constructing Silicon-Substrate Metamaterials**  
*(Cheng Cao, Dexin Ye, Jiangtao Hangfu, Shan Qiao, Changzhi Li, Lixin Ran)*

PAGE 79  
TU3P-22

**Flexible Si BiCMOS on Plastic Substrates**  
*(Jung-Hun Seo, Kan Zhang, Weidong Zhou, Zhenqiang Ma)*

Not  
Available  
TU3P-23

**60V P- and NMOS Transistors and Schottky Diodes Compatible with SiGe BiCMOS and Sub-22nm CMOS Technology without Drain Current Degradation and Heating Effects at Higher Voltages for Mixed-Signal VLSI Applications**  
*(James Pan, David Lawson, Robert Prematta, Tom Shutt, Scott Suko, Tom Knight)*

## TU4C: Efficient RF Power Generation

*Chair: Harish Krishnaswamy, Columbia University — Co-Chair: Nils Pohl, Ruhr-University Bochum*

*Venue: Remington, 15:40 - 17:20, Tuesday, 17 January 2017*

---

Not  
Available  
TU4C-1

**RF Power Generation Using Digitally-Tuned CMOS Technologies**  
*(Jennifer Kitchen)*

PAGE 85  
TU4C-2

**A 28-nm CMOS 76–81-GHz Power Amplifier for Automotive Radar Applications**  
*(Nader Rohani, Jing Zhang, Jaeyoung Lee, Jian Bai)*

PAGE 88  
TU4C-3

**A 20–30GHz High Efficiency Power Amplifier IC with an Adaptive Bias Circuit in 130-nm SiGe BiCMOS**  
*(Cuilin Chen, Xiao Xu, Xin Yang, Tsuyoshi Sugiura, Toshihiko Yoshimasu)*

PAGE 91  
TU4C-4

**A 28-nm CMOS 40-GHz High-Resolution Digitally Controlled Oscillator for Automotive Radar Applications**  
*(Jian Bai, Jaeyoung Lee, Jing Zhang, Nader Rohani)*

## WE1C: Technology, Devices & Modeling

Chair: Paul Hurwitz, TowerJazz — Co-Chair: Parha Chakraborty, NXP Semiconductors

Venue: Remington, 08:00 - 09:40, Wednesday, 18 January 2017

---

- PAGE 94  
WE1C-1      **Experimental Verification of TCAD Simulation for High-Performance SiGe HBTs**  
(Julian Korn, Holger Rücker, Bernd Heinemann)
- PAGE 97  
WE1C-2      **A Novel Device for Low Noise Amplification in 130nm High Resistivity RFSOI Technology Platform**  
(Shyam Parthasarathy, Xi Sung Loo, Jen Shuang Wong, Tao Sun, Rui Tze Toh, Shaoqiang Zhang, Kok Wai Chew, Purakh Raj Verma)
- PAGE 100  
WE1C-3      **Modeling of SiGe HBTs with ( $f_T$ ,  $f_{max}$ ) of (340, 560)GHz Based on Physics-Based Scalable Model Parameter Extraction**  
(Andreas Pawlak, Michael Schroter)
- PAGE 103  
WE1C-4      **A D-Band Tuner for in-situ Noise and Power Characterization in BiCMOS 55nm**  
(Simon Bouvot, Alice Bossuet, Thomas Quémerais, Guillaume Ducournau, François Danneville, Estelle Lauga-Larroze, Daniel Gloria, Jean-Michel Fournier, Christophe Gaquière)
- PAGE 107  
WE1C-5      **A D-Band Passive Receiver with 10dB Noise Figure for in-situ Noise Characterization in BiCMOS 55nm**  
(Simon Bouvot, Thomas Quémerais, Joao Carlos Azevedo Goncalves, Sylvie Lépilliet, Guillaume Ducournau, François Danneville, Daniel Gloria)

## WE2C: Advanced Wireless Transceiver

Chair: Ahmet Cagri Ulusoy, Michigan State University — Co-Chair: Tian Wei Huang, National Taiwan University

Venue: Remington, 10:10 - 11:50, Wednesday, 18 January 2017

---

- PAGE 111  
WE2C-1      **Fully-Integrated Non-Magnetic Non-Reciprocal Components Based on Linear Periodically-Time-Varying Circuits**  
(Negar Reiskarimian, Harish Krishnaswamy)
- PAGE 115  
WE2C-2      **A 15GHz 4-Channel Transmit/Receive RF Core-Chip for High SHF Wide-Band Massive MIMO in 5G**  
(Koji Tsutsumi, Wataru Yamamoto, Takaya Maruyama, Takanobu Fujiwara, Ichiro Somada, Tatsuya Hagiwara, Eiji Taniguchi, Mitsuhiro Shimosawa)
- PAGE 118  
WE2C-3      **A Low Power Programmable Dual-Slope ADC for Single-Chip RFID Sensor Nodes**  
(Hengying Shan, Steve Rausch, Alice Jou, Nathan J. Conrad, Saeed Mohammadi)
- PAGE 121  
WE2C-4      **Programmable-Gain Constant-IF-Bandwidth SiGe BiCMOS Upconversion Micromixer at 2.4/5.8GHz Using Current-Mode Approach**  
(Jin-Siang Syu, Wei-Ling Chang, Chinchun Meng, Yi-Chen Lin, Guo-Wei Huang)